

Amended Specification

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Page 42, second paragraph:

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The semiconductor light-emitting device 62 has a light-transmitting surface 62a and a light reflecting surface 62b. The grating 70e and the light-reflecting surface 4b form an optical cavity for the light generating module 60. The reflectivity of the light-reflecting surface 4b is greater than that of the light-transmitting surface 4a. The reflectivity of the light-transmitting surface 4a is faced to the light-receiving surface 8a of the semiconductor light-receiving device 8.

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